

CD74FCT543

BiCMOS FCT Interface Logic, Octal Register/Transceiver, Three-State

**NOT RECOMMENDED
FOR NEW DESIGNS**
Use CMOS Technology

Features

- Buffered Inputs
- Typical Propagation Delay: 6.4ns at $V_{CC} = 5V$,
 $T_A = 25^\circ C$, $C_L = 50pF$
- Noninverting
- Family Features
 - SCR Latchup Resistant BiCMOS Process and

Circuit Design

- Speed of Bipolar FAST™/AS/S
- 64mA Output Sink Current
- Output Voltage Swing Limited to 3.7V at $V_{CC} = 5V$
- Controlled Output Edge Rates
- Input/Output Isolation to V_{CC}
- BiCMOS Technology with Low Quiescent Power

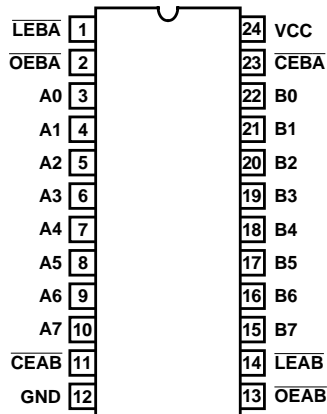
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CD74FCT543EN	0 to 70	24 Ld PDIP	E24.3
CD74FCT543M	0 to 70	24 Ld SOIC	M24.3
CD74FCT543SM	0 to 70	24 Ld SSOP	M24.209

NOTE: When ordering the suffix M and SM packages, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.

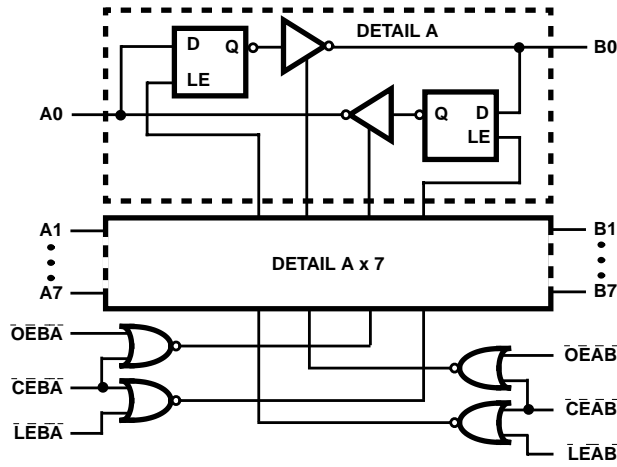
Pinout

CD74FCT543
(PDIP, SOIC, SSOP)
TOP VIEW



CD74FCT543

Functional Diagram



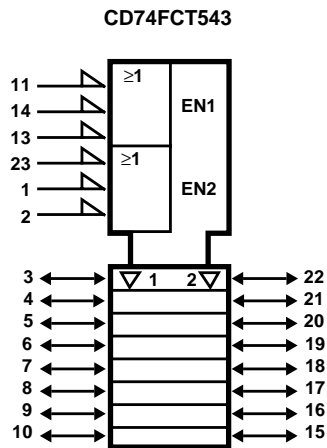
TRUTH TABLE For A to B (Symmetric with B to A)

INPUTS		LATCH STATUS		OUTPUT BUFFERS
CEAB	LEAB	OEAB	A TO B	B0 THRU B7
H	X	X	Storing	High Z
X	H	-	Storing	-
X	-	H	-	High Z
L	L	L	Transparent	Current A Inputs
L	H	L	Storing	Previous A Inputs (Note 1)

NOTE:

1. Before \overline{LEAB} LOW to HIGH Transition
 H = HIGH Voltage Level
 L = LOW Voltage Level
 X = Immaterial
 A to B data flow shown; B to A flow control is the same, except using \overline{CEBA} , \overline{LEBA} , and \overline{OEBA} .

IEC Logic Symbol



CD74FCT543

Absolute Maximum Ratings

DC Supply Voltage (V_{CC})	-0.5V to 6V
DC Input Diode Current, I_{IK} (For $V_I < -0.5V$)	-20mA
DC Output Diode Current, I_{OK} (for $V_O < -0.5V$)	-50mA
DC Output Sink Current per Output Pin, I_O	70mA
DC Output Source Current per Output Pin, I_O	-30mA
DC V_{CC} Current (I_{CC})	140mA
DC Ground Current (I_{GND})	528mA

Thermal Information

Thermal Resistance (Typical, Note 2)	θ_{JA} ($^{\circ}C/W$)
PDIP Package	75
SOIC Package	75
SSOP Package	125
Maximum Junction Temperature	150 $^{\circ}C$
Maximum Storage Temperature Range	-65 $^{\circ}C$ to 150 $^{\circ}C$
Maximum Lead Temperature (Soldering 10s)	300 $^{\circ}C$ (SOIC and SSOP-Lead Tips Only)

Operating Conditions

Operating Temperature Range (T_A)	0 $^{\circ}C$ to 70 $^{\circ}C$
Supply Voltage Range, V_{CC}	4.75V to 5.25V
DC Input Voltage, V_I	0 to V_{CC}
DC Output Voltage, V_O	0 to $\leq V_{CC}$
Input Rise and Fall Slew Rate, dt/dv	0 to 10ns/V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

- θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications Commercial Temperature Range 0 $^{\circ}C$ to 70 $^{\circ}C$, V_{CC} Max = 5.25V, V_{CC} Min = 4.75V

PARAMETER	SYMBOL	TEST CONDITIONS		V_{CC} (V)	AMBIENT TEMPERATURE (T_A)				UNITS
		V_I (V)	I_O (mA)		25 $^{\circ}C$		0 $^{\circ}C$ TO 70 $^{\circ}C$		
					MIN	MAX	MIN	MAX	
High Level Input Voltage	V_{IH}			4.75 to 5.25	2	-	2	-	V
Low Level Input Voltage	V_{IL}			4.75 to 5.25	-	0.8	-	0.8	V
High Level Output Voltage	V_{OH}	V_{IH} or V_{IL}	-15	Min	2.4	-	2.4	-	V
Low Level Output Voltage	V_{OL}	V_{IH} or V_{IL}	64	Min	-	0.55	-	0.55	V
High Level Input Current	I_{IH}	V_{CC}		Max	-	0.1	-	1	μA
Low Level Input Current	I_{IL}	GND		Max	-	-0.1	-	-1	μA
Three-State Leakage Current	I_{OZH}	V_{CC}		Max	-	0.5	-	10	μA
	I_{OZL}	GND		Max	-	-0.5	-	-10	μA
Input Clamp Voltage	V_{IK}	V_{CC} or GND	-18	Min	-	-1.2	-	-1.2	V
Short Circuit Output Current (Note 3)	I_{OS}	$V_O = 0$ V_{CC} or GND		Max	-60	-	-60	-	mA
Quiescent Supply Current, MSI	I_{CC}	V_{CC} or GND	0	Max	-	8	-	80	μA
Additional Quiescent Supply Current per Input Pin TTL Inputs High, 1 Unit Load	ΔI_{CC}	3.4V (Note 4)		Max	-	1.6	-	1.6	mA

NOTES:

- Not more than one output should be shorted at one time. Test duration should not exceed 100ms.
- Inputs that are not measured are at V_{CC} or GND.
- FCT Input Loading: All inputs are 1 unit load. Unit load is ΔI_{CC} limit specified in Electrical Specifications table, e.g., 1.6mA Max. at 70 $^{\circ}C$.

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Switching Specifications Over Operating Range FCT Series $t_p, t_f = 2.5\text{ns}$, $C_L = 50\text{pF}$, R_L (Figure 4)

PARAMETER	SYMBOL	V _{CC} (V)	25°C	0°C TO 70°C			UNITS
			TYP	MIN	TYP	MAX	
Propagation Delays							
An ↔ Bn	t _{PLH} , t _{PHL}	5	6.4	2.5	-	8.5	ns
$\overline{\text{LEBA}}$ to An or $\overline{\text{LEAB}}$ to Bn	t _{PLH} , t _{PHL}	5	9.4	2.5	-	12.5	ns
CEBA or CEAB to An or Bn	t _{PLZ} , t _{PHZ}	5	6.8	2	-	9	ns
	t _{PZL} , t _{PZH}	5	9	2	-	12	ns
Power Dissipation Capacitance	C _{PD} (Note 6)	-	49	-	49	-	pF
Minimum (Valley) V _{OHV} During Switching of Other Outputs (Output Under Test Not Switching)	V _{OHV}	5	0.5	-	-	-	V
Maximum (Peak) V _{OLP} During Switching of Other Outputs (Output Under Test Not Switching)	V _{OLP}	5	1	-	-	-	V
Input Capacitance	C _I	-	-	-	-	10	pF
Input/Output Capacitance	C _{I/O}	-	-	-	-	15	pF

NOTE:

6. C_{PD}, measured per flip-flop, is used to determine the dynamic power consumption.
 P_D (per package) = $V_{CC} I_{CC} + \Sigma(V_{CC}^2 f_i C_{PD} + V_O^2 f_O C_L + V_{CC} \Delta I_{CC} D)$ where:
 V_{CC} = supply voltage
 ΔI_{CC} = flow through current x unit load
 C_L = output load capacitance
 D = duty cycle of input high
 f_O = output frequency
 f_I = input frequency

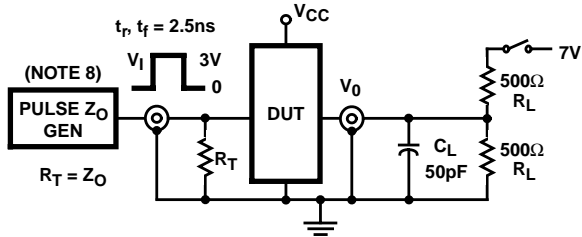
Prerequisite for Switching

PARAMETER	SYMBOL	V _{CC} (V)	25°C	0°C TO 70°C		UNITS
			TYP	MIN	MAX	
Data to Latch Enable Setup Time	t _{SU}	5 (Note 7)	-	3	-	ns
Data to Latch Enable Hold Time	t _H	5	-	2	-	ns
Latch Enable Pulse Width	t _W	5	-	9	-	ns

NOTE:

7. 5V: Minimum is at 4.75V for 0°C to 70°C, Typical is at 5V.

Test Circuits and Waveforms



NOTE:

- 8. Pulse Generator for All Pulses: Rate $\leq 1.0\text{MHz}$; $Z_{OUT} \leq 50\Omega$; $t_r, t_f \leq 2.5\text{ns}$.

FIGURE 1. TEST CIRCUIT

SWITCH POSITION

TEST	SWITCH
t_{PLZ}, t_{PZL} , Open Drain	Closed
$t_{PHZ}, t_{PZH}, t_{PLH}, t_{PHL}$	Open

DEFINITIONS:

C_L = Load capacitance, includes jig and probe capacitance.

R_T = Termination resistance, should be equal to Z_{OUT} of the Pulse Generator.

$V_{IN} = 0\text{V}$ to 3V .

Input: $t_r = t_f = 2.5\text{ns}$ (10% to 90%), unless otherwise specified

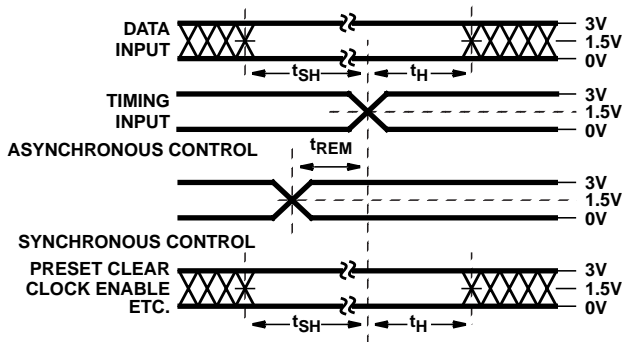


FIGURE 2. SETUP, HOLD, AND RELEASE TIMING

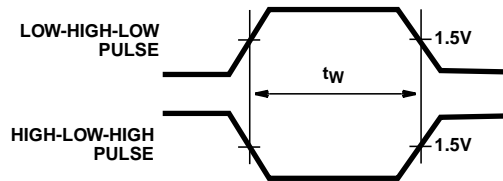


FIGURE 3. PULSE WIDTH

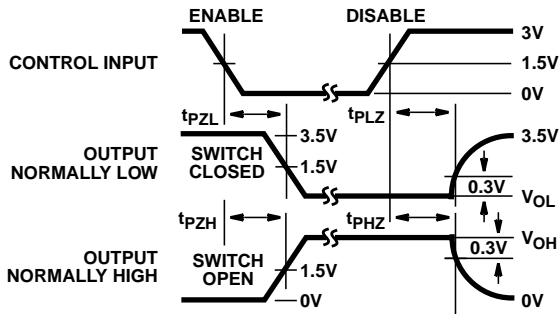


FIGURE 4. ENABLE AND DISABLE TIMING

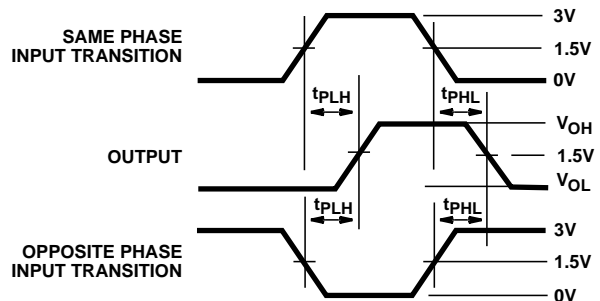
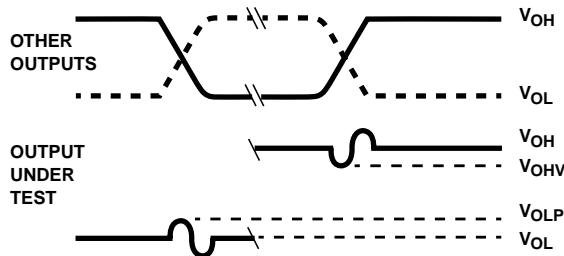


FIGURE 5. PROPAGATION DELAY



NOTES:

- 9. V_{OLP} is measured with respect to a ground reference near the output under test. V_{OHV} is measured with respect to V_{OH} .
- 10. Input pulses have the following characteristics:
 $P_{RR} \leq 1\text{MHz}$, $t_r = 2.5\text{ns}$, $t_f = 2.5\text{ns}$, skew 1ns.
- 11. R.F. fixture with 700MHz design rules required. IC should be soldered into test board and bypassed with $0.1\mu\text{F}$ capacitor. Scope and probes require 700MHz bandwidth.

FIGURE 6. SIMULTANEOUS SWITCHING TRANSIENT WAVEFORMS

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